

PACKAGE MARKING AND ORDERING INFORMATION

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|---------|----------------|-----------|------------|------------|
| SSF6646 | SSF6646 | SOP-8 | Ø330mm | 12mm | 3000 units |

ABSOLUTE MAXIMUM RATINGS(TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|----------------------------------|------------|------|
| Drain-Source Voltage | Vds | 60 | V |
| Gate-Source Voltage | Vgs | ±20 | V |
| | l _D (25℃) | 5 | A |
| Drain Current-Continuous@ Current-Pulsed (Note 1) | I _D (70℃) | 4.3 | A |
| | I _{DM} | 25 | A |
| Maximum Power Dissipation | PD | 2.4 | W |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 175 | °C |

THERMAL CHARACTERISTICS

| | Thermal Resistance, Junction-to-Ambient (Note 2) | R _{0JA} | 62.5 | °C/W |
|--|--|------------------|------|------|
|--|--|------------------|------|------|

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|--------------------------------|-------------------|---|-----|-----|-----|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V Ι _D =250μΑ | 60 | | | V |



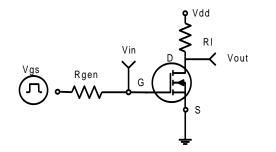
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =1.7A | | 0.8 | 1.2 | V |
|-----------------------------------|---------------------|--|---|-----|------|----|
| DRAIN-SOURCE DIODE CHARACTERIST | ICS | | | | | |
| Gate-Drain Charge | Q _{gd} | | | 4 | | nC |
| Gate-Source Charge | Q _{gs} | V _{DS} =48V,I _D =4.5A,V _{GS} =10V | | 2 | | nC |
| Total Gate Charge | Qg | | | 15 | | nC |
| Turn-Off Fall Time | t _f | | | 6 | | nS |
| Turn-Off Delay Time | t _{d(off)} | I _D =4.5A | | 30 | | nS |
| Turn-on Rise Time | tr | $V_{DS}=30V, V_{GS}=10V, R_{GEN}=3\Omega$ | | 10 | | nS |
| Turn-on Delay Time | t _{d(on)} | | | 13 | | nS |
| SWITCHING CHARACTERISTICS (Note 4 |) | | | | | |
| Reverse Transfer Capacitance | C _{rss} | | | 50 | | PF |
| Output Capacitance | Coss | V _{DS} =25V,V _{GS} =0V, F=1.0MHz | | 100 | | PF |
| Input Capacitance | Clss | | | 700 | | PF |
| DYNAMIC CHARACTERISTICS (Note4) | | | | | | |
| Forward Transconductance | g fs | $V_{DS}=5V,I_{D}=4.5A$ | 5 | | | S |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =4.5A | | 44 | 60 | mΩ |
| Drain-Source On-State Resistance | Р | V_{GS} =4.5V, I _D =3A | | 50 | 75 | mΩ |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 1 | | 3 | V |
| ON CHARACTERISTICS (Note 3) | | | | | | |
| Gate-Body Leakage Current | I _{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | | | ±100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =48V, V_{GS} =0V | | | 1 | μA |

NOTES:

1. Repetitive Rating: Pulse width limited by maximum junction temperature. **2.** Surface Mounted on $1in^2$ FR4 Board, t ≤ 10 sec. **3.** Pulse Test: Pulse Width $\leq 300\mu$ s, Duty Cycle $\leq 2\%$. **4.** Guaranteed by design, not subject to production testing.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



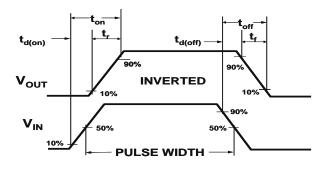


Figure 1:Switching Test Circuit

Figure 2:Switching Waveforms

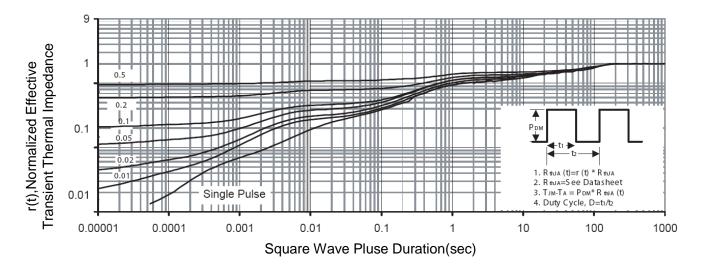
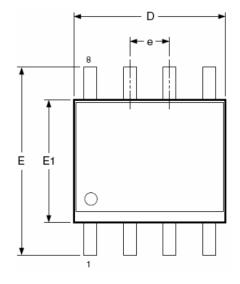
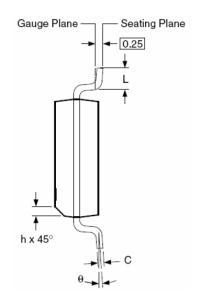


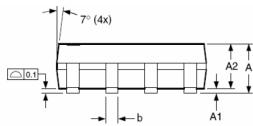
Figure 3 Normalized Maximum Transient Thermal Impedance



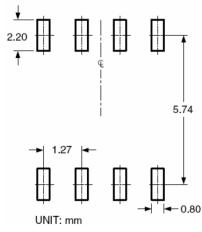
SOP-8 PACKAGE INFORMATION







RECOMMENDED LAND PATTERN



Dimensions in millimeters Symbols Min. Nom. Max. 1.35 1.65 1.75 А A1 0.10 0.25 _ A2 1.25 1.50 1.65 0.31 0.51 b _ 0.25 0.17 С ____ D 4.80 4.90 5.00 E1 3.80 3.90 4.00 1.27 BSC е Е 5.80 6.00 6.20 _ h 0.25 0.50 0.40 1.27 L _ **0**° θ 8° _

4

Dimensions in inches

| 2 | | | | | | | |
|---------|------------|-------|-------|--|--|--|--|
| Symbols | Min. | Nom. | Max. | | | | |
| А | 0.053 | 0.065 | 0.069 | | | | |
| A1 | 0.004 | — | 0.010 | | | | |
| A2 | 0.049 | 0.059 | 0.065 | | | | |
| b | 0.012 | _ | 0.020 | | | | |
| с | 0.007 | _ | 0.010 | | | | |
| D | 0.189 | 0.193 | 0.197 | | | | |
| E1 | 0.150 | 0.154 | 0.157 | | | | |
| e | 0.050 BSC | | | | | | |
| Е | 0.228 | 0.236 | 0.244 | | | | |
| h | 0.010 | _ | 0.020 | | | | |
| L | 0.016 | _ | 0.050 | | | | |
| θ | 0 ° | _ | 8° | | | | |

NOTES:

1. Dimensions are inclusive of plating

Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
Dimension L is measured in gauge plane.

- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.





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